

Nominal:

K 1 kΩ

U 1 kΩ

3 kΩ

20 kΩ

600 Ω

100 Ω

20 mH

0.1 nF

R 20 nF

C 20 nF

K 10 nF

Gr 10 nF

~~47~~ nF

GUBS 33 nF
1 nF

Actual:

0.98395 kΩ

0.97947 kΩ

2.9740 kΩ

9.8860 kΩ

624.80 Ω

99.445 Ω

9.994 mH

0.09562 ~~nF~~ μF

9.640 nF

9.652 nF

9.512 nF

9.425 nF

32.95 nF

0.9830 nF

$$Z_{Th} = 1000 + (10^2 \cdot 10^4 \cdot 2\pi) \\ = 2000 + 628.32 \Omega$$

$$Z_{Load} = 2000 - 628.32 \Omega$$

$$(Load = 16.28 = \frac{1}{\omega C})$$

$$= 25.33 \text{ nF}$$

100

100

100

100

100

100

100

100

100

100

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R _{Load} Ω	V _{Load} theory (mag) (V)	V _{Load} theory (mag) (V)	P _{Load} theory (mag) (W)	P _{Load} Exp (mag) (W)
200	0.909	0.9123	0.00826	8.26
600	3.75	3.708	0.022	23.4
12000 V	5	3.530	4.900	25
3000	7.5	7.503	18.75	28.93
10000	9.091	9.227	8.264	8.612

Load

2 nF	5	0.08482	0.7572	25	0.574
10 nF	5	0.05552	4.345	25	28.88
-23.07 RVIK	5	4.900	25	24.02	23.84
-33 nF	5	4.888	25	25	22.86
0.1 mF	41	4.781	41	41	41

- Q2) The complex conjugate of the source impedance will yield the max. power transfer.
- 2) The load voltages may change due to changing reactance, but the general trend will remain the same.

P_{Load}	Δ	R_{Load}	L_{Load}	C_{Load}
000	•	000	000	231nF
300	•	300	300	33nF
20000	•	20000	20000	200nF
1000	•	1000	1000	23nF
005	•	005	005	005nF

• K: Theoretical values

• R: Experimental